

Sound velocity measurements of hcp Fe-Si alloy at high pressure and high temperature by inelastic X-ray scattering

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ABSTRACT

The sound velocity of hcp Fe_{0.89}Si_{0.11} (Fe-6wt% Si) alloy was measured at pressures from 45 to 84 GPa and temperatures of 300 and 1800 K using inelastic X-ray scattering (IXS) from laser-heated samples in diamond-anvil cells (DACs). The compressional velocity (v_p) and density (ρ) of the Fe-Si alloy are observed to follow a linear relationship at a given temperature. For hcp Fe_{0.89}Si_{0.11} alloy we found $v_p = 1.030 (\pm 0.008) \times \rho - 1.45 (\pm 0.08) + [3.8 \times 10^{-5}(T - 300) \times (\rho - 15.37)]$, including non-negligible temperature dependence. The present results of sound velocity and density of hcp Fe_{0.89}Si_{0.11} alloy indicates that 3–6 wt% of silicon in the inner core with additional amount of Ni can explain the compressional velocity (v_p) and density (ρ) of the “preliminary Earth reference model” (PREM), assuming a temperature of 5500 K and that silicon is the only light element in the inner core

Keywords: Sound velocity, Fe-Si alloy, high pressure, high temperature, inelastic X-ray scattering, inner core, Birch’s law, silicon